



# **EIM6775-4**

**ISSUED 12/22/2008** 

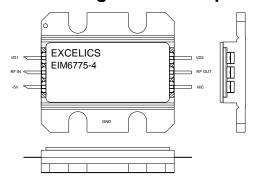
### 6.7 - 7.5 GHz Multi-Stage Power Amplifier

#### **FEATURES**

- 6.7–7.5GHz Operating Frequency Range
- 36.0dBm Output Power at 2dB Compression
- 31.0 dB Typical Power Gain @2dB gain compression
- Non-Hermetic Metal Flange Package

#### **APPLICATIONS**

- Point-to-point and point-to-multipoint radio
- Military Radar Systems





Caution! ESD sensitive device.

### ELECTRICAL CHARACTERISTICS (Tb = 25 °C, 50 ohm, VD1=7V, VD2=10V, Vgg=-5V)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	6.7		7.5	GHz
P2dB	Output Power at 2dB Gain Compression	tput Power at 2dB Gain Compression 35.0 3			dBm
G2dB	Gain @2dB gain compression	gain compression 29			dB
ΔGain	Gain Flatness				dB
Input RL	Input Return Loss		-12	-8	dB
Output RL	Output Return Loss		-15	-10	dB
VD1	Drain Supply Voltage 1		7		V
VD2	Drain Supply Voltage 2		10		V
I <sub>DQ1</sub>	Quiescent Drain Current 1		380		mA
I <sub>DQ2</sub>	Quiescent Drain Current 2		1800	2000	mA
Vgg	Gate Supply Voltage		-5		V
Rth	Thermal Resistance		2.4		°C/W
Tb	Operating Base Plate Temperature	- 30		+ 80	°C



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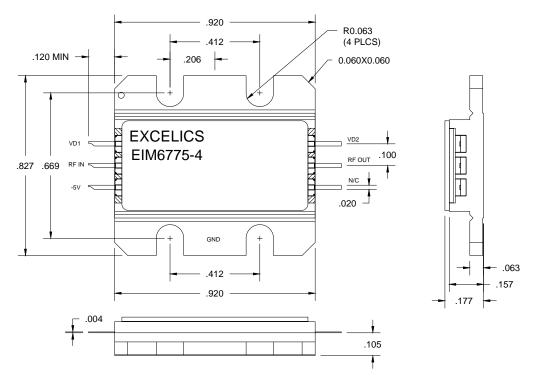
## 6.7 - 7.5 GHz Multi-Stage Power Amplifier

### MAXIMUM RATINGS @25°C1,2

SYMBOL	CHARACTERISTIC	ABSOLUTE	CONTINUOUS 1,2
$V_{D1}$	Drain Supply Voltage <sup>1</sup>	12V	8V
$V_{D2}$	Drain Supply Voltage <sup>2</sup>	14V	10V
$V_{ m gg}$	Gate Supply Voltage	-10V	-6 V
l <sub>gg</sub>	Gate Current	150mA	50 mA
P <sub>IN</sub>	Input Power	20dBm	@ Pout 2dB compression
T <sub>CH</sub>	Channel Temperature	175°C	175°C
T <sub>STG</sub>	Storage Temperature	-65/175°C	-65/175°C
P <sub>T</sub>	Total Power Dissipation	37.5W	37.5W

Notes: 1. Operating the device beyond any of the above rating may reduce MTTF and cause permanent damage.

### **Package Dimension and Pin Assignment**



Dimensions are in inches
\* NC: No connection inside the package

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<sup>2.</sup> Bias conditions must also satisfy the following equation  $Vdd^*Idd < (T_{CH} - Tb)/R_{TH}$ 

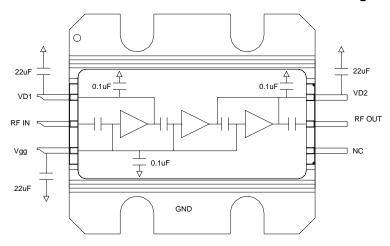


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### **Application Note**

- 1. The package should be screwed onto a good heat sink and ground
- 2. Turn on/off sequence is required:
  - ---to turn on: apply -5V first, then +7V and +10V.
  - ---to turn off: turn +7V and +10V off first, then turn -5V off
- 3. Recommended External Bias Circuit and Internal Block Diagram



### **Typical Performance:**

**TBD** 

#### S-PARAMETERS

**TBD** 

#### **DISCLAIMER**

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.